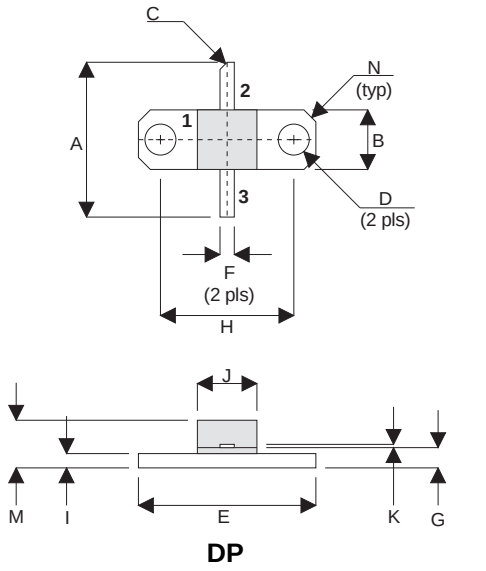
TetraFET

D2202UK

ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA



DP

PIN 1 SOURCE PIN 2 DRAIN

PIN 3 GATE

DIM	Millimetres	Tol.	Inches	Tol.
A	16.51	0.25	0.650	0.010
B	6.35	0.13	0.250	0.005
C	45°	5°	45°	5°
D	3.30	0.13	0.130	0.005
E	18.92	0.05	0.745	0.002
F	1.52	0.13	0.060	0.005
G	2.16	0.13	0.085	0.005
H	14.22	0.05	0.560	0.002
I	1.52	0.13	0.060	0.005
J	6.35	0.13	0.250	0.005
K	0.10	0.02	0.004	0.001
M	5.08	0.51	0.200	0.02
N	1.27 x 45°	0.13	0.050 x 45°	0.005

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 5W – 12.5V – 1GHz SINGLE ENDED

FEATURES

- **SIMPLIFIED AMPLIFIER DESIGN**
- **SUITABLE FOR BROAD BAND APPLICATIONS**
- **LOW C_{rss}**
- **SIMPLE BIAS CIRCUITS**
- **LOW NOISE**
- **HIGH GAIN – 10 dB MINIMUM**

APPLICATIONS

- VHF/UHF COMMUNICATIONS from 1 MHz to 2 GHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25℃ unless otherwise stated)

P_D	Power Dissipation	29W
BV_{DSS}	Drain – Source Breakdown Voltage	40V
BV_{GSS}	Gate – Source Breakdown Voltage	±20V
$I_{D(sat)}$	Drain Current	4A
T_{stg}	Storage Temperature	–65 to 150℃
T_j	Maximum Operating Junction Temperature	200℃

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.
E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk

Document Number 2686
Issue 3

D2202UK

ELECTRICAL CHARACTERISTICS (T_{case} = 25℃ unless otherwise stated)

Parameter		Test Conditions			Min.	Typ.	Max.	Unit
BV_{DSS}	Drain–Source Breakdown Voltage	V_{GS} = 0	I_D = 10mA		40			V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 12.5V	V_{GS} = 0				2	mA
I_{GSS}	Gate Leakage Current	V_{GS} = 20V	V_{DS} = 0				1	µA
$V_{GS(th)}$	Gate Threshold Voltage*	I_D = 10mA	V_{DS} = V_{GS}		1		7	V
g_{fs}	Forward Transconductance*	V_{DS} = 10V	I_D = 0.4A		0.36			mhos
G_{PS}	Common Source Power Gain	P_O = 5W			10			dB
η	Drain Efficiency	V_{DS} = 12.5V	I_{DQ} = 0.2A		40			%
VSWR	Load Mismatch Tolerance	f = 1GHz			20:1			—
C_{iss}	Input Capacitance	V_{DS} = 0V	V_{GS} = –5V	f = 1MHz			24	pF
C_{oss}	Output Capacitance	V_{DS} = 12.5V	V_{GS} = 0	f = 1MHz			20	pF
C_{rss}	Reverse Transfer Capacitance	V_{DS} = 12.5V	V_{GS} = 0	f = 1MHz			2	pF

* Pulse Test: Pulse Duration = 300 µs , Duty Cycle ≤ 2%

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

$R_{THj–case}$	Thermal Resistance Junction – Case	Max. 6.0℃ / W

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.
E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk

Document Number 2686
Issue 3

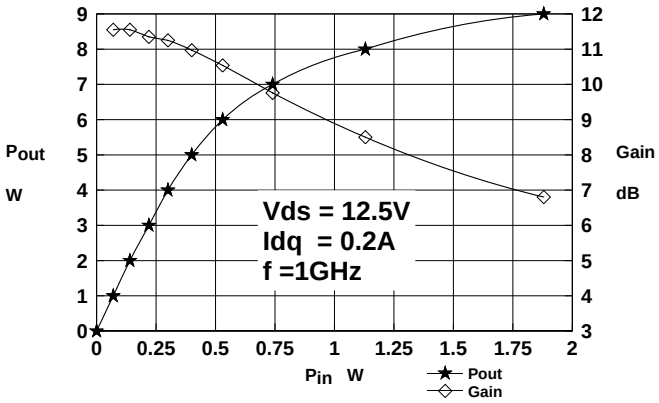


Figure 1
Output Power and Gain vs. Input Power

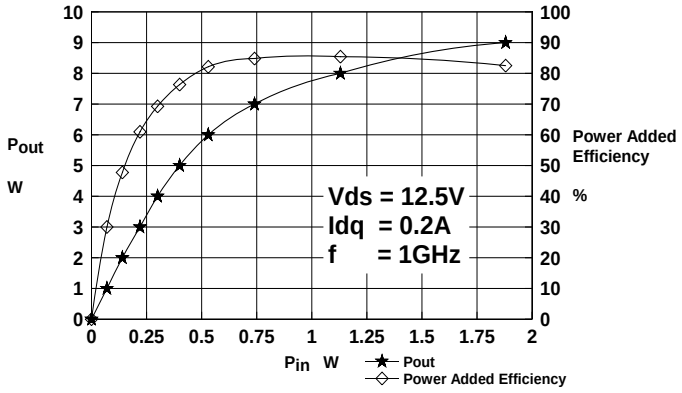


Figure 2
Efficiency vs. Output Power

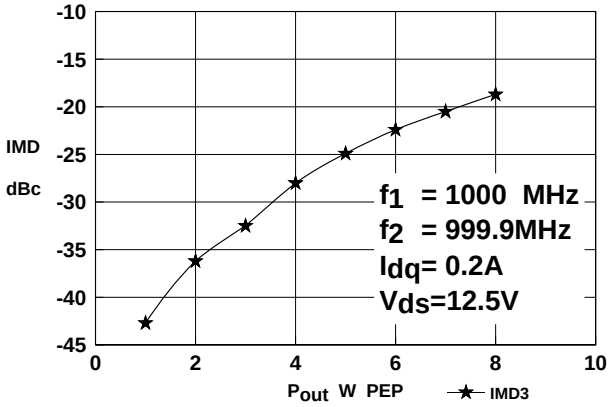


Figure 3
IMD3 vs. Output Power

OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency MHz	Z_S Ω	Z_L Ω
1000	4.0 - j27.0	4.7 - j28.7

Typical S Parameters

! V_{DS} = 28V, I_{DQ} = 0.4A

MHZ S MA R 50

!Freq !MHz	S11 mag	ang	S21 mag	ang	S12 mag	ang	S22 mag	ang
100	0.79	-93.3	16.4	116.9	0.032	24.7	0.66	-90.5
200	0.73	-126.4	8.8	85.7	0.031	2.6	0.67	-123.5
300	0.74	-140.7	5.8	71.7	0.027	-4.7	0.72	-137.7
400	0.77	-151.9	4.1	59.9	0.022	-7.4	0.75	-146.7
500	0.79	-160.0	3.2	52.1	0.017	-2.0	0.79	-153.1
600	0.83	-168.4	2.6	40.3	0.013	13.6	0.82	-158.3
700	0.85	-175.2	2.1	29.8	0.012	38.2	0.84	-163.9
800	0.87	177.8	1.5	22.6	0.015	61.7	0.85	-170.1
900	0.88	172.9	1.2	24.0	0.021	77.9	0.87	-175.2
1000	0.89	167.4	1.2	19.9	0.030	81.0	0.87	-179.7

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.
E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk

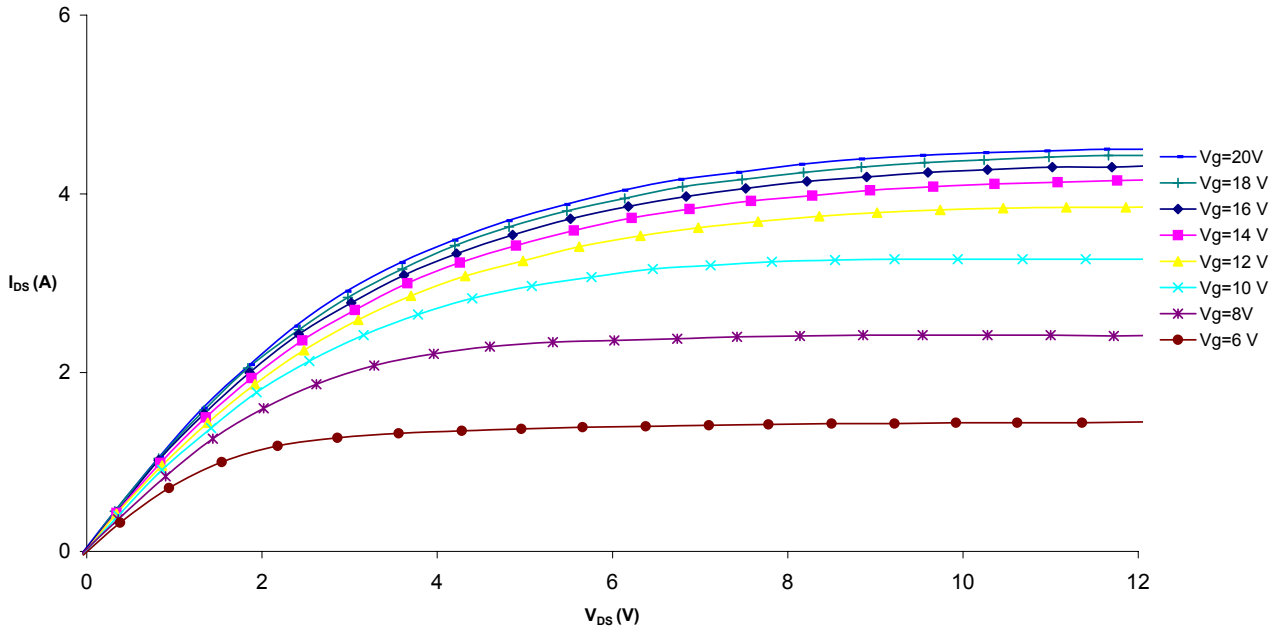


Figure 4 – Typical IV Characteristics.

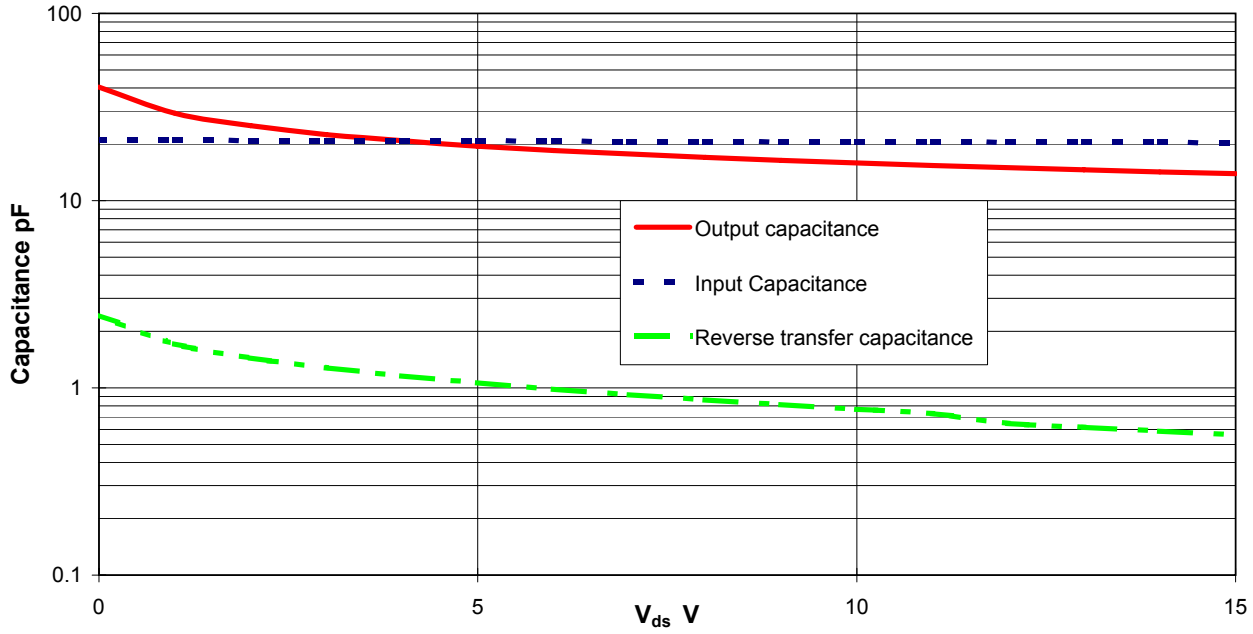
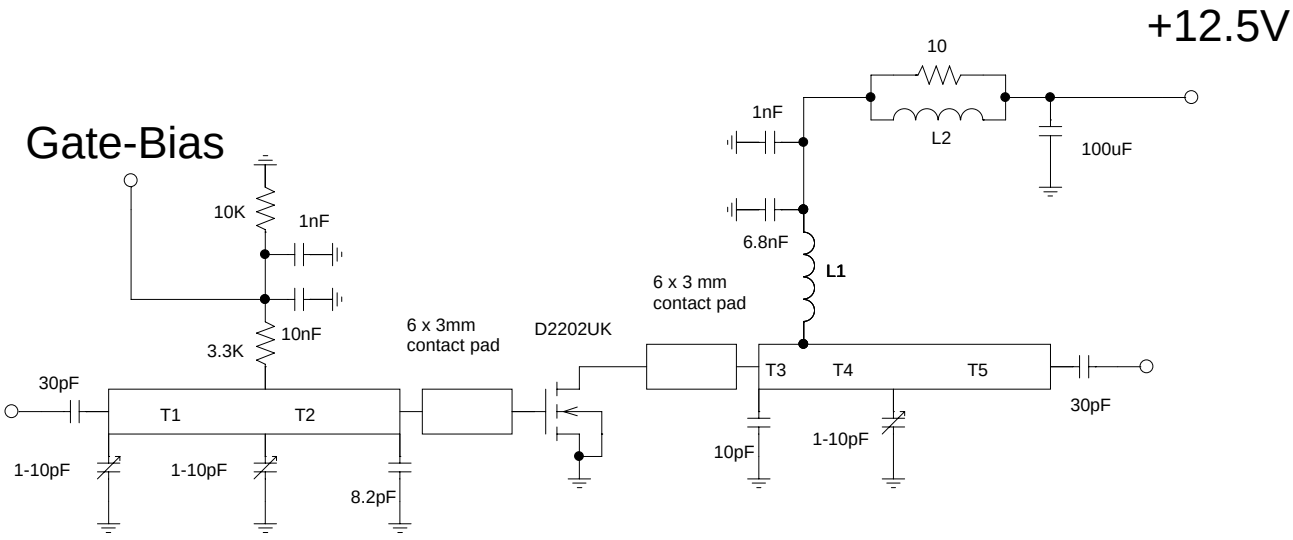


Figure 5 – Typical CV Characteristics.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.
E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk

D2202UK



Substrate 0.8mm PTFE/glass, Er=2.5

All microstrip lines W=2.2mm

T1 35mm

T2 15mm

T3 4mm

T4 14 mm

T5 32mm

L1 7.5 turns 24swg enamelled copper wire, 3mm i.d.

L2 1.5 turns 24swg enamelled copper wire on ferrite core

D2202UK 1GHz Test Fixture

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.
E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk

Document Number 2686
Issue 3